

Solutions for Energy Storage Systems (ESS)



Energy storage is an integral component of electricity generation, transmission, distribution as well as consumption



Before-the-Meter

- Conventional and renewables generation combined with ESS (stationary ESS)
- Transmission and distribution system with bulk ESS (stationary / mobile ESS)

Behind-the-Meter

Roof top PV, UPS, V2G (stationary / mobile ESS)

Generation Transmission Consumption

Bulk storage, substation, utility wind & utility photovoltaic (PV)

Commercial, residential PV & charging stations



On a high level Energy Storage Systems can be categorized in...

Behind-the-Meter



Commercial & residential

- Installed in offices, factories and supermarkets mostly for self consumption
- Excessive non self consumed energy generated by rooftop PV is stored in batteries for later consumption

Before-the-Meter



Intermittent renewables

- Boom in wind and solar PV leading to massive weather-dependent fluctuations and distributed generation, hence mismatch of supply and demand is growing
- ESS is needed to smooth-out this fluctuations



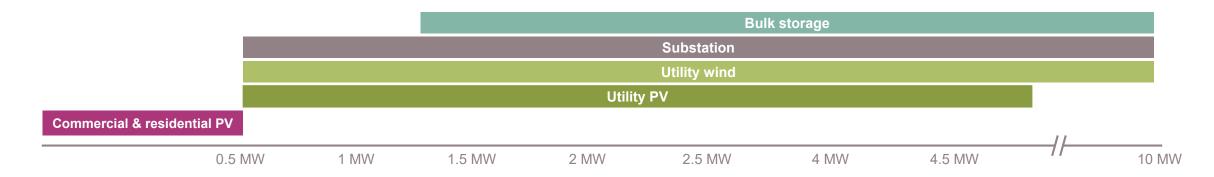
Transmission capacity constraints

 Growing demand on electricity, especially during peak periods (e.g. aircon use at noon etc.), stretching grids to the limit



Grid reliability & stability

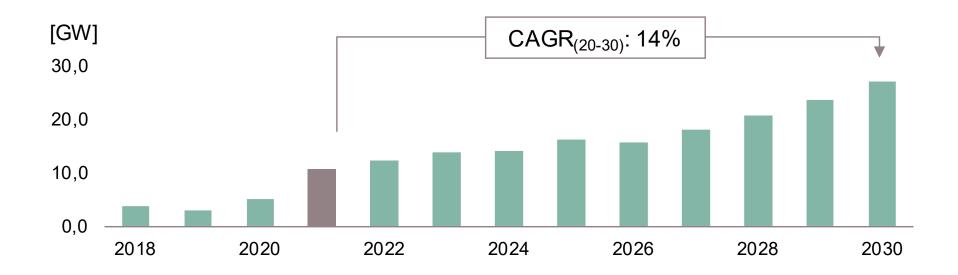
- Unstable grids and full-blown blackouts due to natural disasters and technical problems in ageing infrastructures
- Through ESS grid reliability and stability can be ensured even





Countries around the world look to decarbonize their power sectors

Annual energy storage installations (GW) 1)

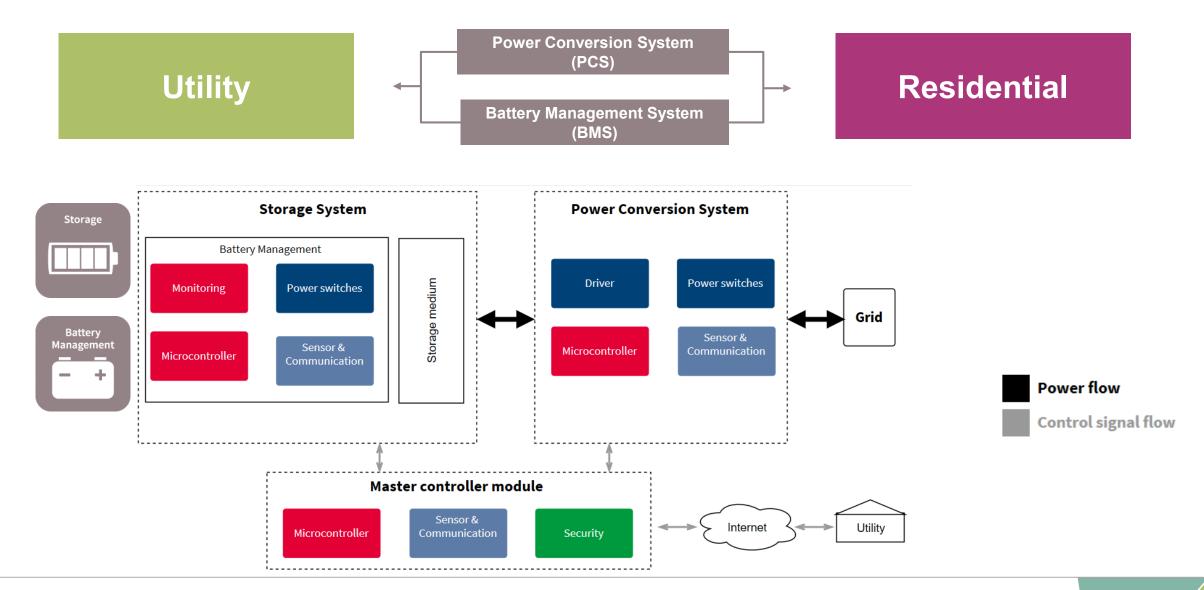


- Global power conversion system shipments are predicted to grow to reach over 11 GW in 2025
- > The front-of-the-meter segment is predicted to account for 62% of total shipments in 2025 and will reach >7.0 GW
- > Significant demand increase in United States due to strong uptake in utility-scale solar plus storage

Source: 1) IHS Markit, "Grid-connected Energy Storage Market Tracker H2 2020", January 2021









Energy Storage Systems – Infineon's wide array of offerings

Battery/ Energy Storage Media

Monitoring and Balancing IC
Protection FETs

Auxiliary Power Supply

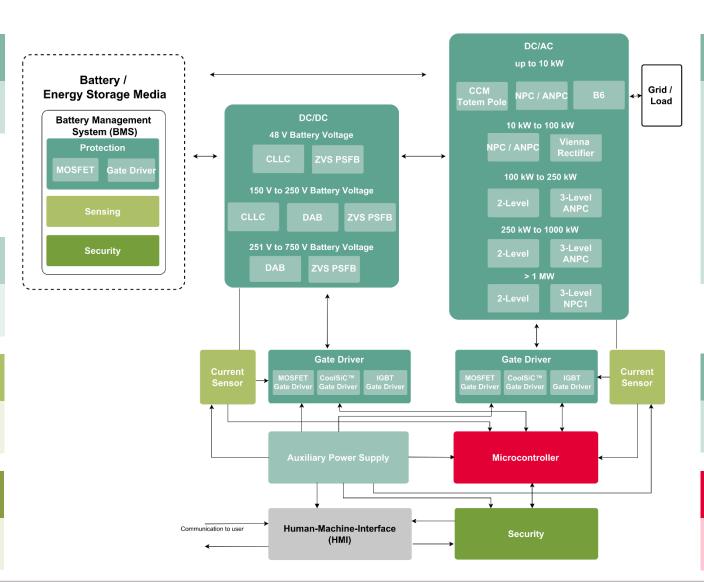
CoolSiC™

Current sensor

XENSIV™

Security

OPTIGA™



Discretes and modules MOSFET / SiC / IGBT

DiscretesModulesCoolMOS™Easy

OptiMOS™ 62 mm

CoolSiC™ MOSFET EconoDUAL™

CoolSiC™ Schottky PrimePACK™

diode

CoolSiC™ Hybrid

Discretes

TRENCHSTOP™

IGBT

Gate Driver

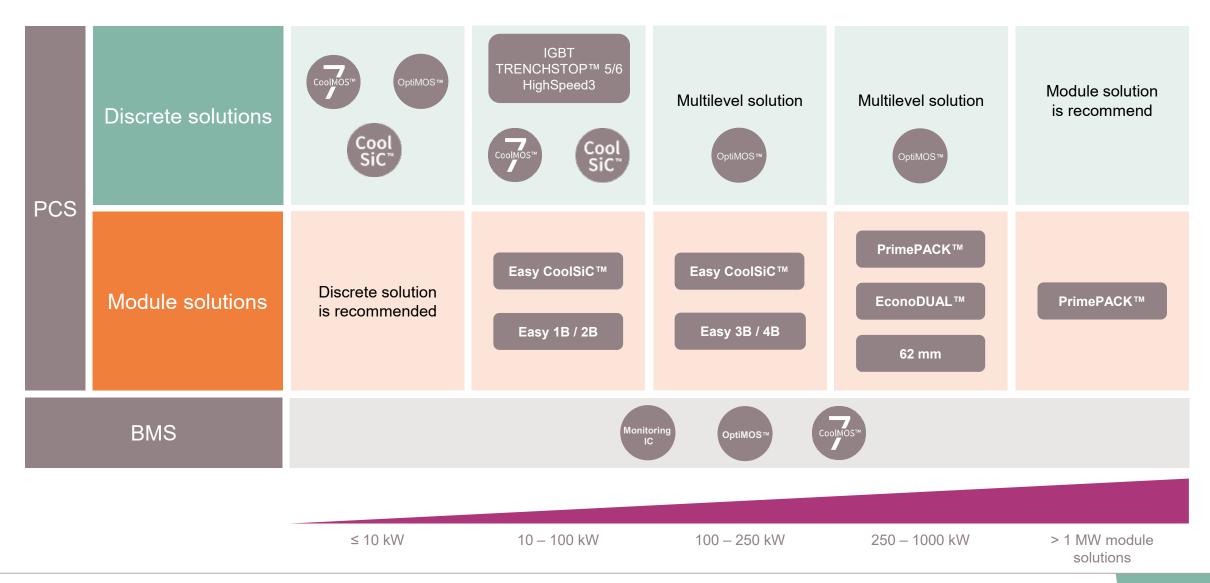
EiceDRIVER™

Microcontroller

XMC™ AURIX™



Infineon's power solution offerings for Energy Storage Systems



CoolSiC[™] helps to reduce energy losses leading to some extra energy, available when needed





Advantages of SiC

As the battery bank makes up the major portion of the total system costs for Energy Storage Systems (ESS), a change from super-junction MOSFET to 1200 V CoolSiC™ MOSFET can lead to approx. 2% extra energy without increasing battery size

Our CoolSiC™ MOSFET 1200 V cutting losses by 50% for extra energy



Coupling topologies for residential Energy Storage Systems

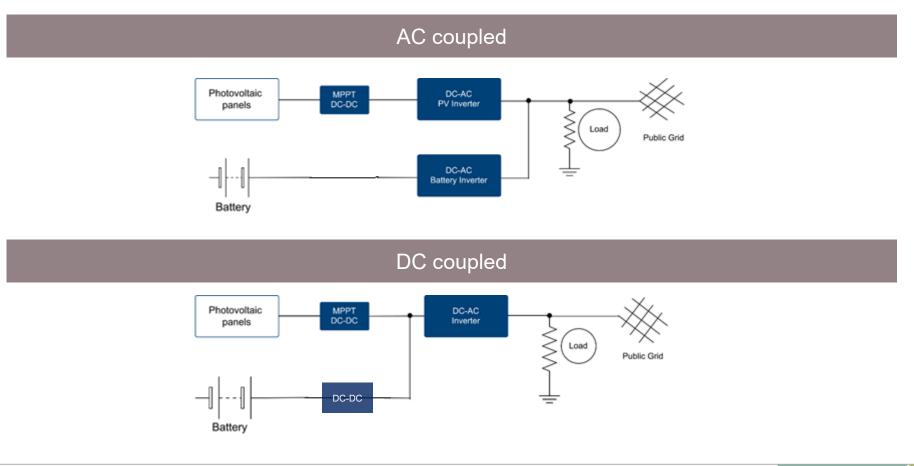


Power rating

~ 1 kW

10 kW

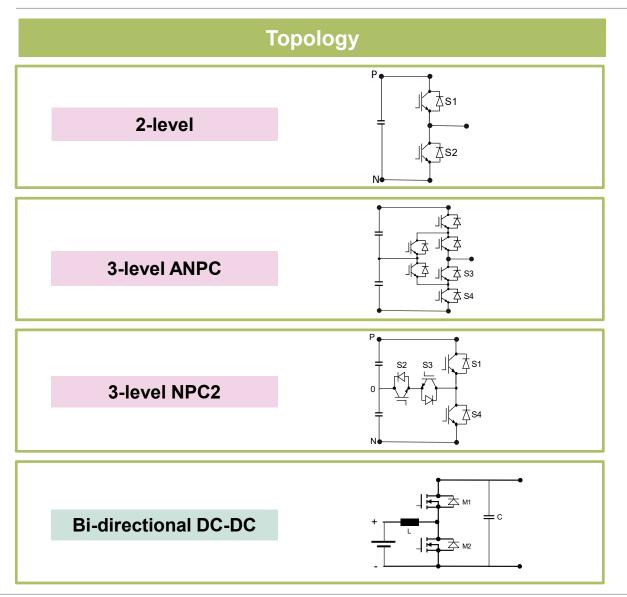
There are two main system coupling topologies for residential ESS, which usually come along with PV installations. Those can be either AC coupled systems or DC coupled



Infineon's suitable solutions for different topologies in the range from



> 10 kW and <125 kW



Features and Infineon's offerings

AC coupled

- Battery voltage <1000 V
 - CoolSiC[™] module 1200 V half-bridge (2-level)
 - Easy CoolSiC[™] 3-level (3-level NPC2)

- Battery voltage 1200 V, 1300V
 - 1700 V half-bridge module
 - 3-level ANPC module

DC coupled

Battery voltage <1000 V: CoolSiC[™] module 1200 V

Infineon's suitable solutions for different topologies in the range from >125 kW and up to 2 MW



Topology 3-level NPC1 3-level ANPC 3-level NPC2

Features and Infineon's offerings

- Battery voltage 1000 V, 3-level NPC1
 - 62mm, EconoDUAL™ 3
- Battery voltage 1500 V, 3-level ANPC
 - Easy 3B
 - 62 mm
 - EconoDUAL™ 3
 - PrimePACK™ 3. PrimePACK™ 3+

- Battery voltage 1500 V, 3-level NPC2
 - PrimePACK™ 3+





Application spaces









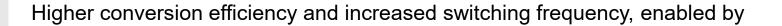






Advanced features

1200 V CoolSiC™ MOSFET:

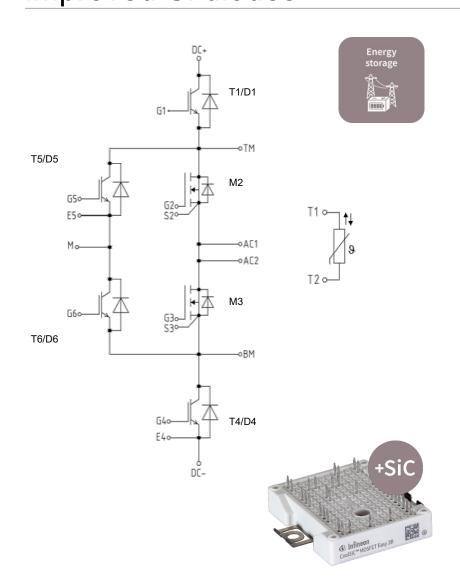




- Lowest RDS(on) in TO247 for highest power density
- > Low and temperature independent switching losses
- Threshold-free on-state → no Vce(sat)
- Intrinsic diode with low reverse recovery charge
- Wide gate-source voltage range from 15 V to 18 V
- Benchmark gate threshold voltage, VGS(th) = 4.5 V
- > -5 to 0 V turn-off gate voltage for easy and simple gate drive
- Robust body diode rated for hard commutation
- > Robustness levels equivalent to silicon IGBTs, through e.g. superior gate oxide reliability

CoolSiC™ MOSFET for ANPC topology in Easy 2B package with improved Si diodes





ВоМ	
M2/M3	1200 V CoolSiC™ MOSFET: 11 mOhm
T1/T4/T5/T6	1200 V IGBT: 100 A Trenchstop 7
D1/D4/D5/D6	1200 V Diode: 100 A Emitter controlled diode 7

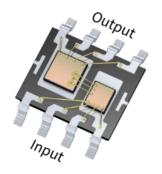
- > ANPC allows optimal integration of CoolSiC™ MOSFET
- > IGBTs are optimized for lowest conduction losses
- Increased Si diode current rating
- No external SiC FWD are needed
- > Power losses independent of power factor
- > Full 1500Vdc capability using 1200V switches

Sales name	Description					
F3L11MR12W2M1H_B74	3-level ANPC Inverter Phase Leg Module					

Every Switch Needs A Driver - The right driver makes a difference







EiceDRIVER™ Enhanced

Up to 2300 V, 9 A DESAT, Miller clamp

Rich feature-set for advanced protection:

- F3 (1ED332x): Cost effective solution with DESAT
- X3 Analog (1ED34xx): Best-in-class DESAT accuracy, Analog Configurability
- X3 Digital (1ED38xx): I2C configurable enabling predictive maintenance



www.infineon.com/gdenhanced



EiceDRIVER™ Compact

Up to 2300 V, 18 A Miller clamp, 2-level slew-rate-control

Reduced feature-set and easy to design-in:

- X3 Compact (1ED31xx): easy to design & cost effective
- 2L-SRC Compact (1ED32xx): EMI & switching loss optimization



www.infineon.com/gdcompact

New products with Reinforced isolation (UL 1577 and VDE-11)







Key features industrial current sensor



Key value



Multiple Options

The TLx4971 offers **broad flexibility** as many settings can be optimized by customers in the application. Additionally pre-programmed devices are available



8 different variants each 120A, 75A, 50A and 25A (UL and non-UL)



Application range

A bandwidth of 240kHz, the intrinsic linearity and the very low insertion resistance of 220 $\mu\Omega$ and less than 1nH inductance allows a wide range applications, in special GaN and SiC applications



Wide range of applications



System compatibility

Stray field robust design with differential measurement of magnetic field allows accurate measurement with parallel or multiple current rails



Optimized for **parallel measurement**e.g. multiple phases



Cost optimization

Reduced BOM cost due to two integrated OCD (Over-Current Detection) pins with less than 1µs reaction time and a small 8x8mm power package



Lower costs due to less external components and small package size



Robust design

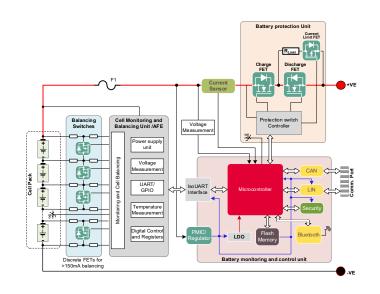
Enables galvanic isolated measurement for **high voltage** and **high current applications** without heat sink due to the **superior thermal heat dissipation**



Galvanic isolation plus outstanding thermal performance







Key functionalities



Protection



Performance optimization



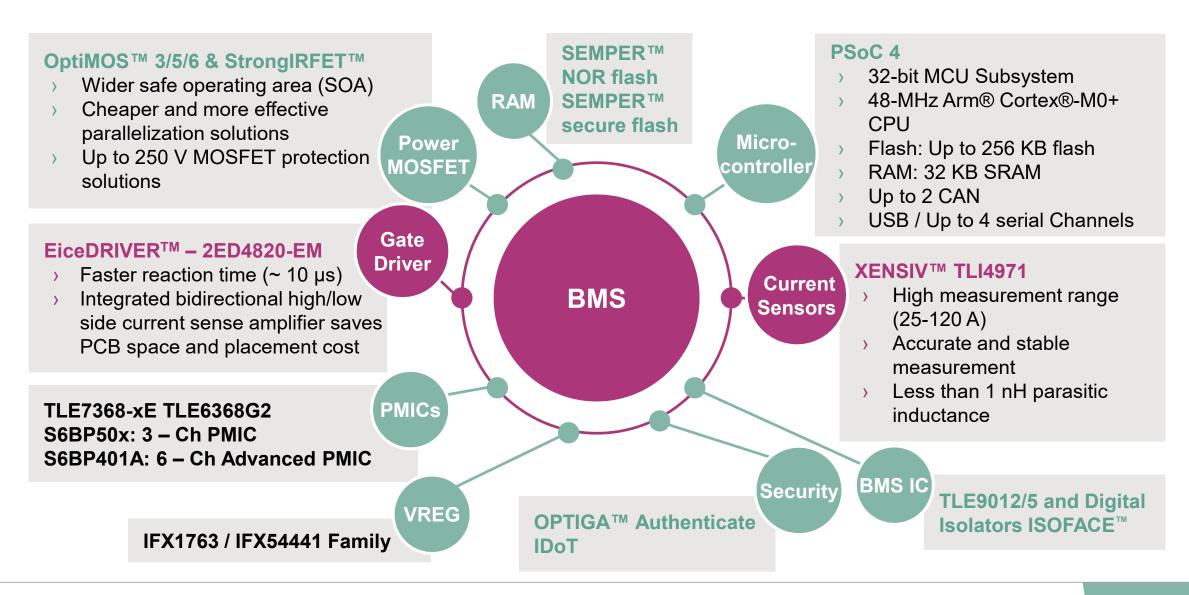
Battery state calculation

BMS functions

Battery protection				Cell monitoring and balancing (CMB)							
Over charge / Deep discharge	Inrus	h current	Short circuit	Thermal management	Cell volta monitorin balancir	g &	Temperature monitoring		Battery pack voltage monitoring		Current monitoring
Battery monitoring and control (BMC)			Security		Logging		Regulators		Communication		
Fuel gauging	SOH	soc	Inter- communication	Authentication	Encryption	Data storage		Voltage regulators	PMICs	Wired	l Wireless

BMS Offerings





Benefit from Infineon's comprehensive portfolio to solve your Energy Storage Systems design requirements







Part of your life. Part of tomorrow.